

# DATA SHEET

# SILICON TRANSISTOR ARRAY $\mu$ PA1436A

# NPN SILICON POWER TRANSISTOR ARRAY HIGH SPEED SWITCHING USE (DARLINGTON TRANSISTOR) INDUSTRIAL USE

### DESCRIPTION

The  $\mu$ PA1436A is NPN silicon epitaxial Darlington Power Transistor Array that built in 4 circuits designed for driving solenoid, relay, lamp and so on.

### **FEATURES**

- Easy mount by 0.1 inch of terminal interval.
- High hre for Darlington Transistor.
- C-E Reverce Diode built in.
- High Speed Switching.

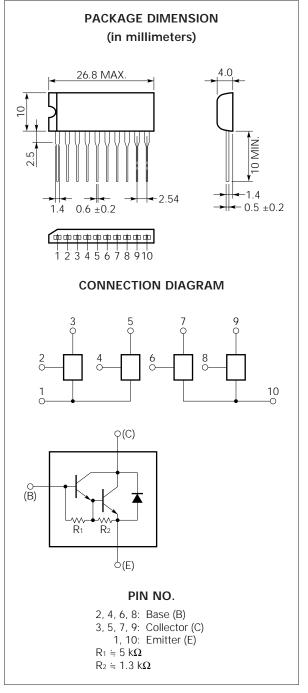
### ORDERING INFORMATION

Part Number	Package	Quality Grade		
μΡΑ1436AH	10 Pin SIP	Standard		

Please refer to "Quality grade on NEC Semiconductor Device" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

### ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

	•					
Collector to Base Voltage	Исво	150	V			
Collector to Emitter Voltage	Vceo	100	V			
Emitter to Base Voltage	Vево	8	V			
Collector Current (DC)	IC(DC)	±3	A/unit			
Collector Current (pulse)	C(pulse)*	±5	A/unit			
Base Current (DC)	B(DC)	0.3	A/unit			
Total Power Dissipation	PT1**	3.5	W			
(Ta = 25 °C)						
Total Power Dissipation	PT2**	28	W			
(T <sub>c</sub> = 25 °C)						
Junction Temperature	Tj	150	°C			
Storage Temperature	Tstg -55	5 to +150	°C			
* PW $\leq$ 350 $\mu$ s, Duty Cycle $\leq$ 2 %						
** 4 Circuits						



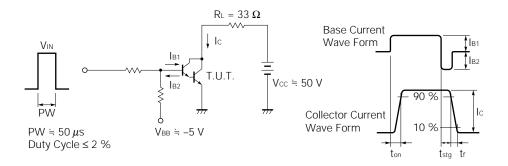
The information in this document is subject to change without notice.

# ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

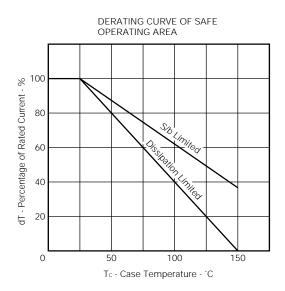
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Collector Leakage Current	Ісво			1	μA	$V_{CB} = 100 V$ , $I_E = 0$	
Emitter Leakage Current	Ево			5	mA	$V_{EB} = 5 V$ , Ic = 0	
DC Current Gain	hfei *	2000		20000	_	Vce = 2 V, Ic = 1.5 A	
DC Current Gain	hfe2 *	1000			—	$V_{CE} = 2 V$ , $I_C = 3 A$	
Collector Saturation Voltage	V <sub>CE(sat)</sub> *		1	1.5	V	Ic = 1.5 A, Iв = 1.5 mA	
Base Saturation Voltage	V <sub>BE(sat)</sub> *		1.8	2	V	Ic = 1.5 A, Iв = 1.5 mA	
Turn On Time	ton		0.3		μs	Ic = 1.5 A	
Storage Time	tstg		1.5		μs	$I_{B1} = -I_{B2} = 3 \text{ mA}$ - $V_{CC} \doteq 50 \text{ V}, \text{ R}_{L} = 33 \Omega$ See test circuit	
Fall Time	tr		0.4		μs		

\* PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2 % /pulsed

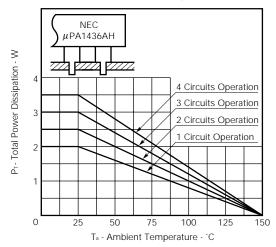
## SWITCHING TIME TEST CIRCUIT

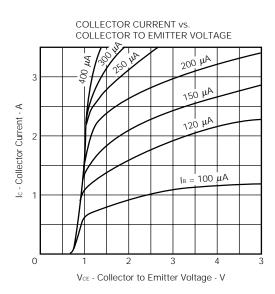


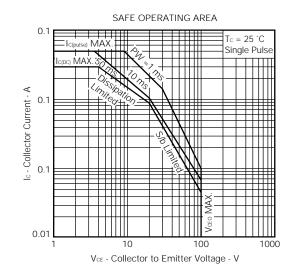
TYPICAL CHARACTERISTICS (Ta = 25 °C)



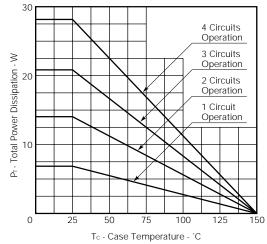
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



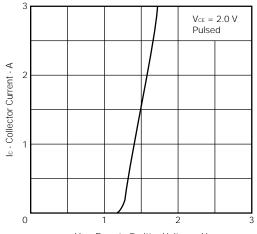




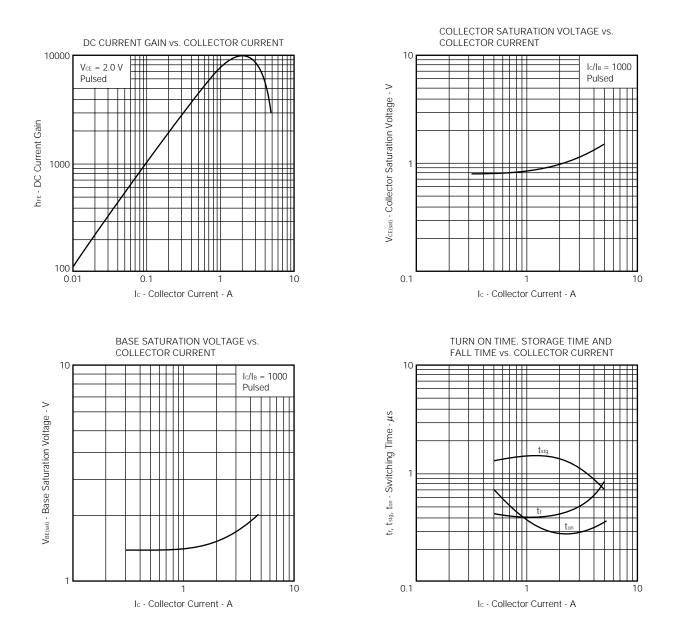
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE







# REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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